NSN 5961-01-307-8443

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View Online at https://aerobasegroup.com/nsn/5961-01-307-8443 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 800.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 1.8 watts small-signal input power, common-collector preset **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 10001-2905205 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization:

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